

# HD74LV1GW17A

## **Dual Buffer with Schmitt Trigger Inputs**

REJ03D0079-0100Z (Previous ADE-205-709 (Z)) Rev.1.00 Sep.12.2003

#### **Description**

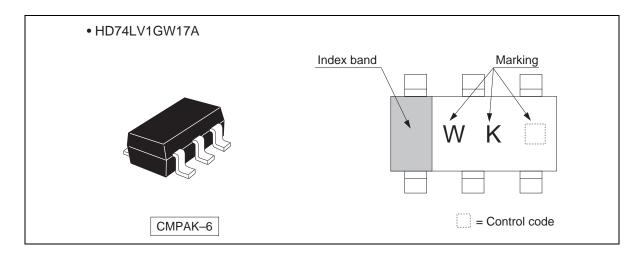
The HD74LV1GW17A has dual buffer with schmitt-trigger input in a 6 pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

#### **Features**

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Supply voltage range : 1.65 to 5.5 V Operating temperature range : -40 to +85°C
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V to 5.5 V) All outputs  $V_{O}$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V)
- Output current  $\pm 6$  mA (@V<sub>CC</sub> = 3.0 V to 3.6 V),  $\pm 12$  mA (@V<sub>CC</sub> = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV1GW17ACME	CMPAK-6 pin	CMPAK-6V(O)	СМ	E (3,000 pcs / Reel)

#### **Outline and Article Indication**

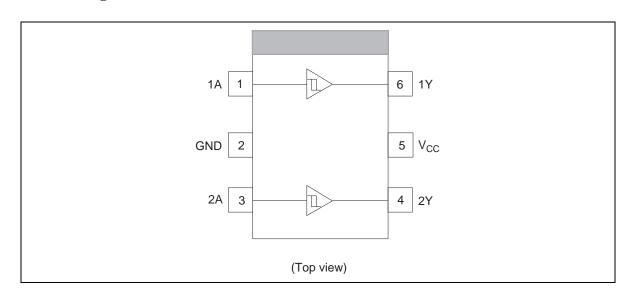


#### **Function Table**

Input A	Output Y
Н	Н
L	L

H : High level L : Low level

### **Pin Arrangement**



#### **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V	
Input voltage range *1	Vı	-0.5 to 7.0	V	
Output voltage range *1, 2	Vo	$-0.5$ to $V_{CC}$ + 0.5	V	Output : H or L
		-0.5 to 7.0		V <sub>CC</sub> : OFF
Input clamp current	I <sub>IK</sub>	-20	mA	V <sub>I</sub> < 0
Output clamp current	I <sub>OK</sub>	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	Io	±25	mA	$V_O = 0$ to $V_{CC}$
Continuous current through V <sub>CC</sub> or GND	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air) *3	P <sub>T</sub>	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

### **Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V <sub>CC</sub>	1.65	5.5	V	
Input voltage range	VI	0	5.5	V	
Output voltage range	Vo	0	Vcc	V	
Output current	I <sub>OL</sub>	_	1	mA	V <sub>CC</sub> = 1.65 to 1.95 V
		_	2	<del></del>	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		_	6		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	12	<del></del>	$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
	I <sub>OH</sub>	_	-1	_	$V_{CC} = 1.65 \text{ to } 1.95 \text{ V}$
		_	-2		$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		_	-6	_	$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	-12	_	$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	Ta	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

#### **Electrical Characteristic**

•  $Ta = -40 \text{ to } 85^{\circ}\text{C}$ 

Item	Symbol	V <sub>CC</sub> (V) *	Min	Тур	Max	Unit	Test condition
Threshold	V <sub>T</sub> <sup>+</sup>	1.65 to 1.95	_	_	V <sub>CC</sub> ×0.75	V	
voltage		2.5	_	_	1.75	-	
		3.3	_	_	2.31	-	
		5.0	_	_	3.50	-	
	V <sub>T</sub>	1.65 to 1.95	V <sub>CC</sub> ×0.25	_	_	=	
		2.5	0.75	_	_	=	
		3.3	0.99	_	_	=	
		5.0	1.5	_	_	=	
	$\Delta V_T$	1.65 to 1.95	0.1	_	V <sub>CC</sub> ×0.4	=	
		2.5	0.25	_	1.0	=	
		3.3	0.33	_	1.32	=	
		5.0	0.5	_	2.0	=	
Output voltage	V <sub>OH</sub>	Min to Max	V <sub>CC</sub> -0.1	_	_	V	I <sub>OH</sub> = -50 μA
		1.65	1.4	_	_	=	$I_{OH} = -1 \text{ mA}$
		2.3	2.0	_	_	=	$I_{OH} = -2 \text{ mA}$
		3.0	2.48	_	_	=	I <sub>OH</sub> = -6 mA
		4.5	3.8	_	_	=	I <sub>OH</sub> = -12 mA
	V <sub>OL</sub>	Min to Max	_	_	0.1	=	I <sub>OL</sub> = 50 μA
		1.65	_	_	0.3	=	I <sub>OL</sub> = 1 mA
		2.3	_	_	0.4	=	I <sub>OL</sub> = 2 mA
		3.0	_	_	0.44	=	I <sub>OL</sub> = 6 mA
		4.5	_	_	0.55	=	I <sub>OL</sub> = 12 mA
Input current	I <sub>IN</sub>	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Quiescent supply current	Icc	5.5	_	_	10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
Output leakage current	I <sub>OFF</sub>	0	_	_	5	μΑ	$V_{IN}$ or $V_O = 0$ to 5.5 $V$
Input capacitance	C <sub>IN</sub>	3.3		3.0		pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

### **Switching Characteristics**

## $\bullet \quad V_{CC} = 1.8 \pm 0.15 \ V$

Item	Symbol	Ta = 2	25°C	$5^{\circ}$ C Ta = -40 to 85°C		Unit		FROM	TO	
		Min	Тур	Max	Min	Max	_	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	16.8	32.0	1.0	34.0	ns	C <sub>L</sub> = 15 pF	Α	Υ
delay time	t <sub>PHL</sub>	_	23.8	43.0	1.0	46.0		C <sub>L</sub> = 50 pF		

### $\bullet \quad V_{CC} = 2.5 \pm 0.2 \ V$

Item	Symbol	Ta = 2	Ta = $25^{\circ}$ C Ta = $-40 \text{ to } 85^{\circ}$ C		Unit		FROM	TO		
		Min	Тур	Max	Min	Max	_	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	10.5	19.7	1.0	22.0	ns	C <sub>L</sub> = 15 pF	A	Υ
delay time	t <sub>PHL</sub>	_	14.0	24.0	1.0	27.0	-	C <sub>L</sub> = 50 pF	=	

### • $V_{CC} = 3.3 \pm 0.3 \text{ V}$

Item	Symbol	Ta = 2	25°C Ta = -40 to 85°C		Unit		FROM	ТО		
		Min	Тур	Max	Min	Max	='	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	8.3	12.8	1.0	15.0	ns	C <sub>L</sub> = 15 pF	Α	Υ
delay time	t <sub>PHL</sub>	_	10.8	16.3	1.0	18.5	=	$C_L = 50 pF$	=	

### $\bullet \quad V_{CC} = 5.0 \pm 0.5 \ V$

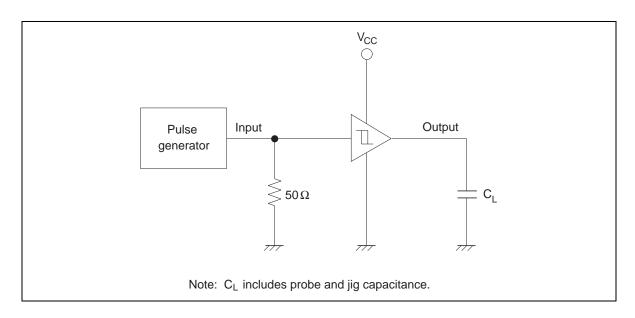
Item	Symbol	Ta = 2	25°C	C Ta = $-40 \text{ to } 85^{\circ}\text{C}$		Unit	Test	FROM	то	
		Min	Тур	Max	Min	Max		Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	_	5.5	8.6	1.0	10.0	ns	C <sub>L</sub> = 15 pF	Α	Υ
delay time	$t_{PHL}$	_	7.0	10.6	1.0	12.0	=	C <sub>L</sub> = 50 pF	<del>_</del>	

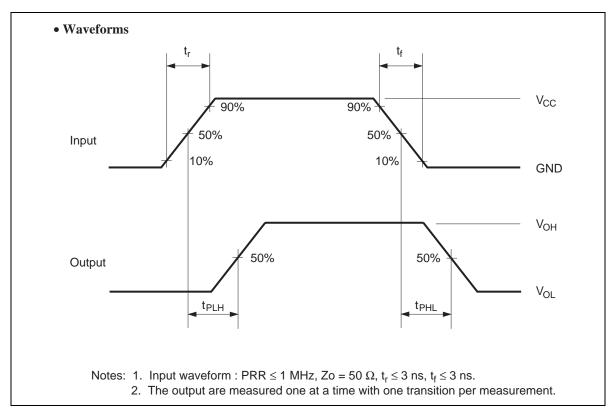
### **Operating Characteristics**

### • $C_L = 50 \text{ Pf}$

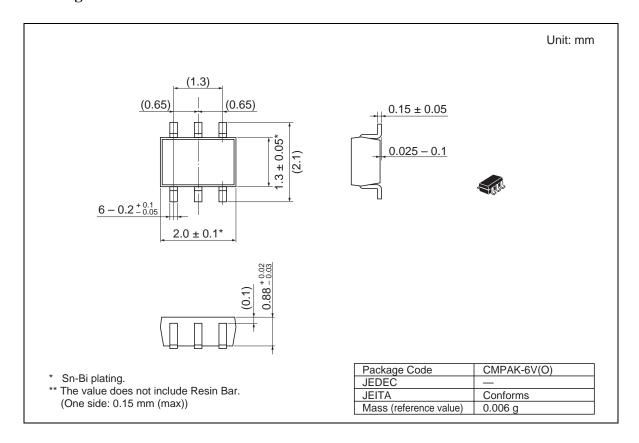
Item	Symbol	V <sub>CC</sub> (V)	Ta = 25°C			Unit	<b>Test Conditions</b>	
			Min	Тур	Max	_		
Power dissipation	$C_{PD}$	3.3	_	8.5	_	pF	f = 10 MHz	
capacitance		5.0	_	10.0	_	_		

#### **Test Circuit**





### **Package Dimensions**



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